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TELEPHONE SPEECH NETWORK IC

■ GENERAL DESCRIPTION

The NJM2105 is a Telephone Speech Network IC produced in a 9-pin single-in-line package which complies with foreign regulations such as FCC and DOC rules.

This IC incorporates adjustable transmit, receive and sidetone functions, a DC loop interface circuit, tone dialer interface and a regulated output voltage for a pulse/tone dialer. Also included is a gain control circuit to keep constant transmition/reception levels under loop current variations.

External components around this IC are minimized and it is the most suitable speech network IC for a compact size portable telephone.

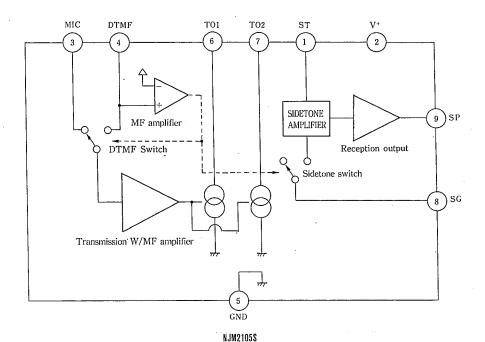
■ FEATURES

- Operates with 20 to 120 mA of loop current
- Either voice signal or DTMF is selected for transmission.
- Either line input or DTMF sidetone is selected for receiver output.
- DTMF sidetone level can be controlled by external components (C, R).
- ECM, Magnetic, Dynamic, Ceramic etc., type are applicable for MIC.
- Dynamic, Ceramic etc., type are applicable for receiver.
- Due to wide operation voltage from 2.5 to 15 volts, parallel phone performance is excellent, 600, 601 type are possible to connect in parallel.
- SIP-9 with minimum external components.
- Package Outline SIP9
- Bipolar Technology

■ PACKAGE OUTLINE



■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25℃)

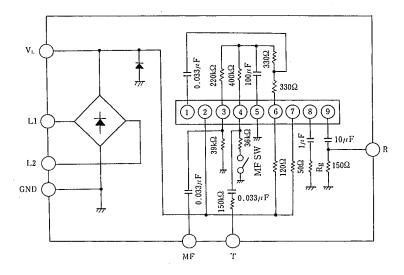
| PARAMETER | SYMBOL | RATINGS | UNIT | |
|-----------------------------|--------|----------|------|--|
| Line voltage | VL | 20 | V | |
| Line current | lı. | 300 | mA | |
| Power dissipation | Po | 700 | mW | |
| Operating Temperature Range | Topr | -20~+75 | °C | |
| Storage Temperature Range | Tstg | -40~+125 | °C | |

■ ELECTRICAL CHARACTERISTICS

(V+=5V, Ta=25°C)

| PARAMETER | SYMBOL | FIG. | CONDITION | MIN. | TYP. | MAX. | UNIT |
|-----------------------------|-----------------|------|---------------------------------------|-------|------|----------|------------------|
| Line voltage | VL | 1 | I _L =20mA | 3.0 | 3.5 | 4.0 | V |
| 5 | | 1 | $I_L = 120 \text{mA}$ | 10.5 | 11.5 | 13.5 | v |
| Transmission amplifier gain | Gτ | 2 | $I_L = 20 \text{mA}$ | 36.0 | 38.0 | 40.0 | dB |
| | | 2 | $I_L = 120 \text{mA}$ | 36.0 | 38.0 | 40.0 | dB |
| Reception amplifier gain | GR | 4 | I _L =20mA | -10.0 | -8.0 | -6.0 | dB |
| | i l | 4 | I _L = 120mA | 10.0 | -8.0 | -6.0 | dВ |
| MF amplifier gain | G _{MF} | 3 | I _L =20mA | 10.0 | 12.0 | 14.0 | dB . |
| | 1 | 3 | I _L = 120mA | 10.0 | 12.0 | 14.0 | dB |
| Transmission Dynamic Range | DT | 2 | Distortion 4% 1 _L = 20mA | 2.0 | | | V _{P-P} |
| | | 2 | Distortion 4% I _L = 120mA | 5.0 | | _ | V _{P-P} |
| Reception Dynamic Range | DR | 4 | Distortion 10% I _L =20mA | 0.3 | | | V _{P-P} |
| | | 4 | Distortion 10% I _L = 120mA | 0.4 | - | <u> </u> | V _{P-P} |
| Receving Source Current | l _S | | $I_L = 20 \sim 120 \text{mA}$ | 1.0 | - | _ | mA |
| Receiving output | V _{RO} | | $I_L = 20 \sim 120 \text{mA}$ | 1.05 | 1.50 | 1.75 | V |

■ TEST CIRCUITS



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Fig. 1

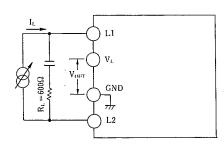


Fig. 2

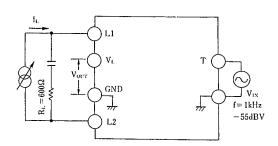


Fig .3

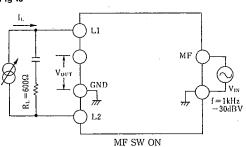
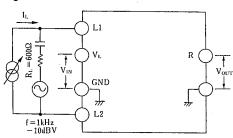
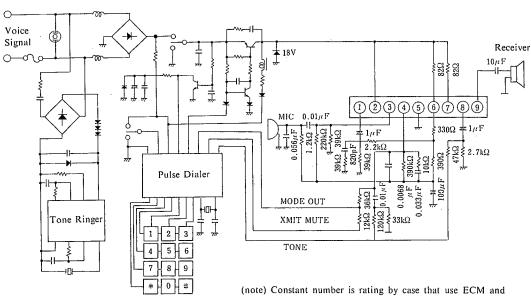


Fig. 4



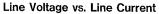
■ TYPICAL APPLICATION

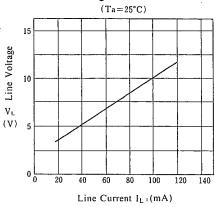


Dynamic Speaker.

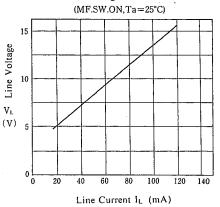
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■ TYPICAL CHARACTERISTICS

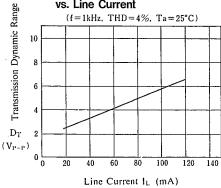




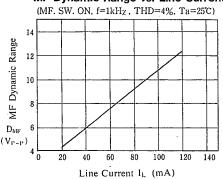
MF Line Voltage vs. Line Current



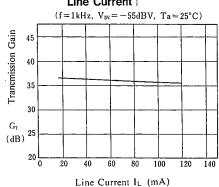
Transmission Dynamic Range vs. Line Current



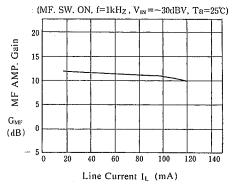
MF Dynamic Range vs. Line Current



Transmission Gain vs. Line Current !

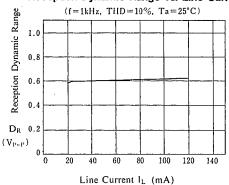


MF AMP. Gain vs. Line Current

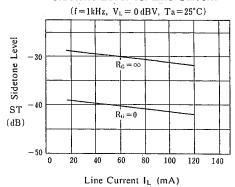


■ TYPICAL CHARACTERISTICS

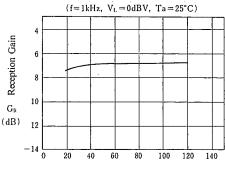
Reception Dynamic Range vs. Line Current



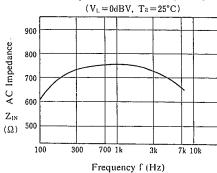
Sidetone Level vs. Line Current



Reception Ganin vs. Line Current



AC Impedance vs. Ferequency



NJM2105

MEMO

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